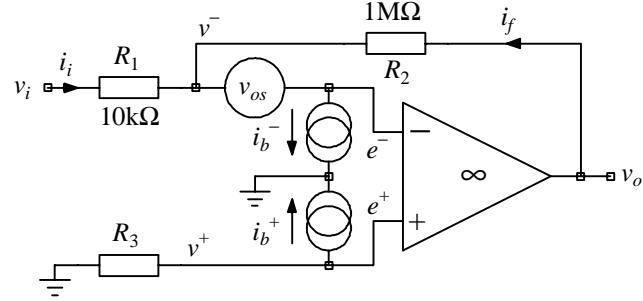


## Electronic Devices in Circuits Tutorial Solutions: Operational Amplifiers

- 1 (i) Since the question is about offset generators, the offset equivalent circuit of the op-amp must be used. The diagram opposite includes an  $R_3$  which in the question equals 0. You can either use the result obtained in lectures, which includes  $R_3$ , and put  $R_3 = 0$  or perform an analysis on the circuit with  $R_3 = 0$  from the outset. The latter approach, which will give you valuable practice in circuit analysis, proceeds as follows:



First sum currents at the  $v^-$  node remembering that the input signal source appears to be its Thevenin equivalent, a short circuit, from an offset analysis point of view,

$$i_i + i_f = i_b^- = \frac{0 - v^-}{R_1} + \frac{v_o - v^-}{R_2} \quad \text{or} \quad v^- = -\frac{R_1 R_2}{R_1 + R_2} \left( i_b^- - \frac{v_o}{R_2} \right) \quad (1.1)$$

Then write down  $e^+$  and  $e^-$ , the inputs to the ideal bit of the op-amp,

$$e^+ = 0 \quad (\text{since } R_3 = 0) \quad \text{and} \quad e^- = v^- + v_{os} \quad (1.2)$$

Assuming the op-amp gain to be infinite,  $e^+ = e^-$ , and combining (1.1) and (1.2) gives;

$$0 = -\frac{R_1 R_2}{R_1 + R_2} \left( i_b^- - \frac{v_o}{R_2} \right) + v_{os}$$

$i_b^-$  can be expressed in terms of specified parameters as  $i_b^- = i_b + i_{os}/2$  which leads to:

$$v_o = \frac{R_1 + R_2}{R_1} \left( i_b \frac{R_1 R_2}{R_1 + R_2} + \frac{i_{os}}{2} \frac{R_1 R_2}{R_1 + R_2} - v_{os} \right) \quad (1.3)$$

(1.3) gives the output voltage due to the offset generators for the condition  $R_3 = 0$ . Note that  $i_{os}$  and  $v_{os}$  are *independent* generators with specified largest magnitudes but *they may be of either polarity*. Thus in order to work out the worst case output you must assume that  $i_{os}$  and  $v_{os}$  are both of the same polarity and will therefore both add to, or subtract from, the effects of  $i_b$ . Thus,

$$v_{o(max)} = 400\text{mV} + 100\text{mV} + 505\text{mV} = 1.005\text{V} \quad \text{and}$$

$$v_{o(min)} = 400\text{mV} - 100\text{mV} - 505\text{mV} = -0.205\text{V}$$

- (ii) If both  $v_{os}$  and  $i_{os}$  were zero, the only effect to remain would be that due to  $i_b$ . Thus from (1.3),

$$v_o = \frac{R_1 + R_2}{R_1} \left( i_b \frac{R_1 R_2}{R_1 + R_2} \right) = i_b R_2 = 400\text{mV}$$

- (iii) In order to answer this part, the analysis of part (i) must be extended to include the effects of a finite  $R_3$ . This can be achieved by recognising that the relationship describing  $e^+$  in (1.2)

must be modified to  $e^+ = -i_b^- R_3$  and that if  $i_b^+ = i_b + i_{os}/2$ ,  $i_b^- = i_b - i_{os}/2$ . The result is as developed in the lecture notes:

$$v_o = \frac{R_1 + R_2}{R_1} \left[ i_b \left( \frac{R_1 R_2}{R_1 + R_2} - R_3 \right) + \frac{i_{os}}{2} \left( \frac{R_1 R_2}{R_1 + R_2} + R_3 \right) - v_{os} \right] \quad (1.4)$$

The  $i_b$  term vanishes when  $R_3 = R_1 // R_2 = 9.9 \text{ k}\Omega$ .

- (iv) When the condition of part (iii) is satisfied, (1.4) reduces to :

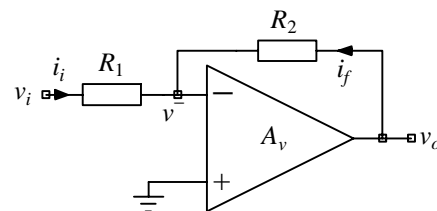
$$v_o = i_{os} R_2 - v_{os} \frac{R_1 + R_2}{R_1}.$$

By inspection of this relationship it is clear that the only way of reducing the effect of  $i_{os}$  by a factor of 10 is to reduce  $R_2$  by a factor of 10. The gain is determined by resistor *ratios* so to maintain the same gain, all the resistors in the circuit must be reduced by the same factor as  $R_2$  - ie 10.

- (v) FETs have very high input resistances and very small input currents because the input is a reverse biased p-n junction in the case of a JFET and an insulated gate in the case of a MOSFET. Op-amps using either type of FET as input devices consequently have very small input currents and very small input offset currents. In such circumstances the dominant offset source is the equivalent input voltage generator.

## 2

Gain-bandwidth product arises as a result of the gain characteristics of the op-amp itself so you must perform an analysis which includes the frequency dependent op-amp gain. You can assume though that the amplifier is perfect in every other respect. The usual starting point is to sum currents at the inverting input node in order to find  $v^-$  in terms of  $v_o$  and  $v_i$  :



$$i_i + i_f = 0 = \frac{v_i - v^-}{R_1} + \frac{v_o - v^-}{R_2} \quad \text{or} \quad v^- = v_o \frac{R_1}{R_1 + R_2} + v_i \frac{R_2}{R_1 + R_2} \quad (2.1)$$

Next use the op-amp equation to express  $v_o$  in terms of  $v^+$  and  $v^-$  .....

$$v_o = A_v (v^+ - v^-) = A_v v^- \quad (\text{since } v^+ = 0) \quad (2.2)$$

Combining (2.1) and (2.2) to eliminate  $v^-$  gives,

$$\frac{v_o}{v_i} = - \frac{\frac{R_2}{R_1 + R_2}}{\frac{1}{A_v} + \frac{R_1}{R_1 + R_2}} \quad (2.3)$$

The op-amp gain is given by

$$A_v = \frac{A_0}{1 + j \frac{\omega}{\omega_0}} \quad (2.4)$$

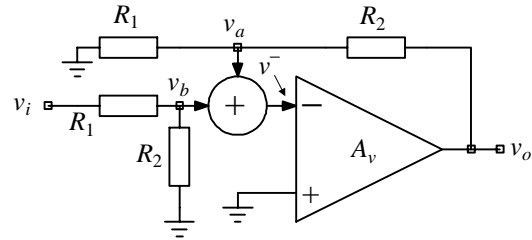
and by using (2.4) in (2.3) and forcing the result to a standard form, the circuit transfer function is

$$\frac{v_o}{v_i} = - \frac{\frac{R_2}{R_1 + R_2}}{\frac{1}{A_v} + \frac{R_1}{R_1 + R_2}} = - \frac{\frac{R_2}{R_1 + R_2}}{\left( \frac{1 + j \frac{\omega}{\omega_0}}{A_0} \right) + \frac{R_1}{R_1 + R_2}} = - \frac{\frac{A_0 R_2}{R_1 + R_2}}{\left( 1 + \frac{A_0 R_1}{R_1 + R_2} \right) \left( 1 + j \frac{\omega}{\omega_0 \left( 1 + \frac{A_0 R_1}{R_1 + R_2} \right)} \right)}$$

$$\equiv \frac{k}{1 + j \frac{\omega}{\omega_1}} \text{ where } k = \frac{\frac{A_0 R_2}{R_1 + R_2}}{\left( 1 + \frac{A_0 R_1}{R_1 + R_2} \right)} \text{ and } \omega_1 = \omega_0 \left( 1 + \frac{A_0 R_1}{R_1 + R_2} \right)$$

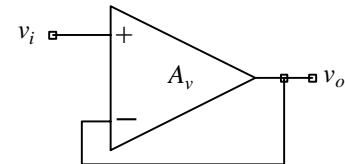
$$\text{Gain-bandwidth product} = k \omega_1 = A_0 \omega_0 R_2 / (R_1 + R_2)$$

This result tells you that for the inverting amplifier circuit connection the gain-bandwidth product of the circuit is not independent of circuit gain. The reason for this can be seen if the circuit is drawn in a formal feedback system form. (2.1) suggests that  $v^-$  is the sum of two potentially divided voltages,  $v_a$  and  $v_b$ .  $v_a$  is the voltage that would appear at  $v^-$  in a non-inverting circuit; the inverting connection has an additional potential divider that converts  $v_i$  into  $v_b$  and it is this potential divider which introduces a gain dependence in the gain-bandwidth product. The effect is exactly the same as it would be if a resistive attenuator were put in front of a conventional non-inverting amplifier circuit and then evaluated the gain-bandwidth product of the combination evaluated.



3

In this question you need to recognise that a voltage follower circuit has a gain very close to unity. Under such circumstances, the gain-bandwidth product is numerically equal to the bandwidth. If you cannot see this, you must work it out .....



$$v_o = A_v (v^+ - v^-) = A_v (v_i - v_o) \quad \text{or} \quad \frac{v_o}{v_i} = \frac{1}{\frac{1}{A_v} + 1}$$

The op-amp gain is approximated by a first order low pass response,  $A_v = A_0 / (1 + j \omega / \omega_0)$  so,

$$\frac{v_o}{v_i} = \frac{1}{\frac{1}{A_v} + 1} = \frac{A_0}{1 + A_0 + j \frac{\omega}{\omega_0}} = \frac{A_0}{1 + A_0} \frac{1}{1 + j \frac{\omega}{\omega_0 (1 + A_0)}} \approx \frac{1}{1 + j \frac{\omega}{\omega_0 A_0}} \text{ for } A_0 \gg 1$$

The -3dB bandwidth of the voltage follower circuit,  $A_0 \omega_0$ , is the gain-bandwidth product of the amplifier.

The phase associated with the voltage follower is  $\phi = -\tan^{-1} \omega/A_0\omega_0 = -\tan^{-1} f/A_0f_0$  and the magnitude of this phase shift must not exceed  $0.1^\circ$  at 50 kHz. Using the phase relationship above, required gain-bandwidth product =  $50\text{kHz} / \tan 0.1^\circ = 28.6\text{MHz}$ .

- 4 (i) The op-amp in question has a step response described by a simple exponential so it is a first order system. The angular -3dB bandwidth of a first order system is the reciprocal of its time constant so the circuit bandwidth is  $1/2.8 \times 10^{-6} = 357\text{krad s}^{-1}$  or 56.8kHz. We are told that the circuit gain at which the exponential response was measured was 250V/V so the gain-bandwidth product is  $56.8\text{kHz} \times 250 = 14.2\text{MHz}$ .

- (ii) If the feedback resistors in the amplifier circuit were changed to give a non-inverting gain of 10V/V the -3dB bandwidth would be (gain-bandwidth product) / (new gain) = 1.42MHz.

- (iii) The system time constant is related to bandwidth as explained in part (i). With a gain of 10V/V, therefore, the time constant is given by  $\tau = 1 / (2\pi \times 1.42 \times 10^6) = 112\text{ns}$ . The circuit rise time is the time it takes the exponential step response of the circuit to travel between 10% and 90% of its start to aiming level range. The relationship between time constant and risetime is something you should know but if you don't, it is not difficult to work out.

$$t_r = \text{risetime} = 2.2\tau = 246\text{ns}$$

- 5 (i) The op-amp will behave like a first order low pass system so if its gain-bandwidth product is 15MHz and the non-inverting circuit gain is 10V/V, the -3dB bandwidth must be  $15\text{MHz} / 10\text{V/V} = 1.5\text{MHz}$ . Its transfer function can be written as,

$$\frac{v_o}{v_i} = k \frac{1}{1+j\frac{\omega}{\omega_0}} = 10 \frac{1}{1+j\frac{f}{1.5 \times 10^6}}$$

At a frequency of 5MHz,  $|\text{gain}| = |v_o/v_i| = 10/(1+(5/1.5)^2)^{0.5} = 10/3.48 = 2.87\text{V/V}$   
and  $\angle [v_o/v_i] = -\tan^{-1} \omega/\omega_0 = -\tan^{-1} 5/1.5 = -73^\circ$ .

- (ii) First identify the maximum rate of change of a sinusoidal waveform,  $v(t) = V_p \sin \omega t$ .  
 $dv(t)/dt = V_p \omega \cos \omega t$  is max when  $\cos \omega t = 1$ , so max rate of change of  $v(t) = V_p \omega$ .  
Equating max rate of change to slew rate and rearranging to express frequency explicitly,

$$f_{\max} = \frac{\text{slew rate}}{2\pi V_p} = \frac{15 \times 10^6}{2\pi \times 10} = 398\text{kHz}.$$

- (iii) The rising and falling edges of a square wave of magnitude  $V_{p,p}$  appearing at the output of an op-amp will be exponential in nature because of the first order system behaviour of the op-amp. There may, however, be a value of system time constant which would cause the initial rate of rise of the exponential to try and exceed the amplifier slew rate. The first thing to do therefore is identify the smallest time constant that can be tolerated by the system if slew rate

limiting is to be avoided. The maximum rate of change of an exponential occurs at  $t = 0$  and is easily shown by a number of means to be  $V_{p-p}/\tau$ . The minimum time constant is thus,

$$\tau_{min} = V_{p-p}/(\text{slew rate}) = 15 / (25 \times 10^6) = 600\text{ns}$$

Using the known gain-bandwidth product and the relationship between  $\tau$  and  $f_0$  for a first order system the circuit gain that will give a  $\tau$  of 600ns can be found. The -3dB bandwidth that corresponds to  $\tau = 600\text{ns}$  is  $f_0 = 1 / (2 \pi \tau) = 265\text{kHz}$ . The gain-bandwidth product divided by the bandwidth gives the amplifier gain that will give a first order system time constant of 600ns.

$$\text{gain} = (\text{gain-bandwidth product}) / (\text{bandwidth}) = 15\text{MHz} / 265\text{kHz} = 56\text{V/V}.$$

If the gain were halved, the bandwidth would be doubled (gain-bandwidth product is constant) and the first order system time constant would be halved. This would make the initial rate of change of the exponential waveform faster than the maximum rate of change that the amplifier could support - ie, the amplifier slew rate - and the exponential would consequently be distorted.

- (iv) The question of part (iii) is based on the premise that the square wave is of a frequency that is sufficiently low to permit the rising and falling exponential edges of the output signal to reach their aiming level. Under such conditions the form of the exponential edges is independent of the frequency of the square wave. If the signal frequency is such that the exponential rising and falling edges are not permitted to reach their aiming levels - ie, the signal half period is of the order of, or less than, the system time constant - the problem can still be worked out but it is harder to find the functional form of the exponentials (because it is harder to identify aiming levels) and the problem becomes very dependent on the square wave frequency.

6

This question is an exercise in time domain analysis. Start as usual by identifying  $v^+$  and  $v^-$  in terms of  $v_o$  and  $v_i$ . By inspection  $v^- = v_o/2$  but to find  $v^+ (= v_C)$ ,  $i_C$  must be found by summing currents at the  $v^+$  node:

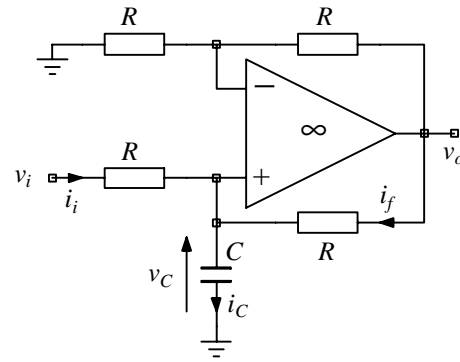
$$i_C = i_i + i_f = \frac{v_i - v_C}{R} + \frac{v_o - v_C}{R}$$

and since  $A_v = \infty$ ,  $v^+ (= v_C) = v^- = v_o/2$ ,

$$i_C = \frac{v_i - v_C}{R} + \frac{v_o - v_C}{R} = \frac{v_i}{R} - \frac{v_o}{2R} + \frac{v_o}{R} - \frac{v_o}{2R} = \frac{v_i}{R}$$

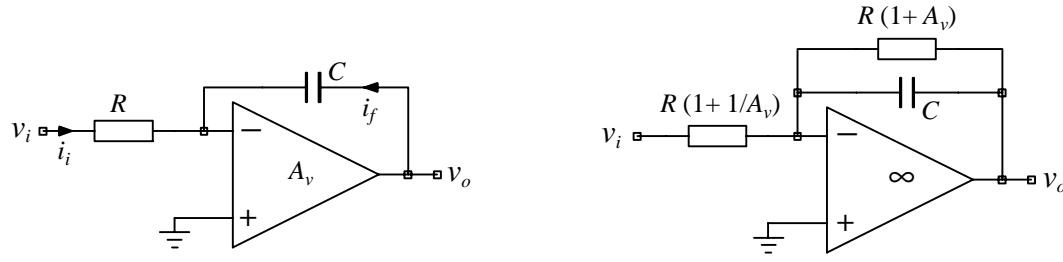
The voltage across  $C$  is given by the integral of the current through it:

$$v_C = \frac{v_o}{2} = \frac{1}{C} \int i_C dt = \frac{1}{C} \int \frac{v_i}{R} dt \text{ or } v_o = \frac{2}{CR} \int v_i dt.$$



7

The easiest approach here is to perform a frequency domain analysis on each circuit to find their transfer functions. The equivalence of the circuits is demonstrated if they have the same transfer function. The same approach could be used with a time domain analysis but time domain analysis is often a slightly more awkward proposition than its frequency domain counterpart.



Beginning with the finite gain model, summing currents at the inverting input node gives:

$$i_i + i_f = \frac{v_i - v^-}{R} + (v_o - v^-) sC = 0 \text{ or } v^- = \frac{v_o sCR + v_i}{1 + sCR} \quad (7.1)$$

Since  $v^+ = 0$ , the op-amp equation,  $v_o = A_v(v^+ - v^-)$  reduces to  $v_o = -A_v v^-$  and this can be used to eliminate  $v^-$  from (7.1) to give,

$$-\frac{v_o}{A_v} = \frac{v_o sCR + v_i}{1 + sCR} \text{ or } v_o \left( \frac{1}{A_v} + \frac{sCR}{1 + sCR} \right) = -\frac{v_i}{1 + sCR} \text{ so}$$

$$\frac{v_o}{v_i} = \frac{-A_v}{1 + sCR(1 + A_v)}$$

The infinite gain model can be dealt with by using the ideal expression for the gain of an inverting amplifier circuit connection:

$$\frac{v_o}{v_i} = -\frac{\frac{R(1 + A_v)}{sC}}{R \left( 1 + \frac{1}{A_v} \right)} = -\frac{\frac{R(1 + A_v)}{sCR(1 + A_v) + 1}}{R \left( 1 + \frac{1}{A_v} \right)} = \frac{-R(1 + A_v)}{(sCR(1 + A_v) + 1) R \left( \frac{A_v + 1}{A_v} \right)}$$

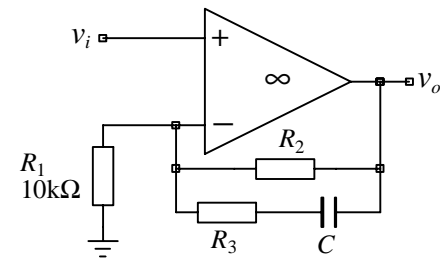
$$= \frac{-A_v}{1 + sCR(1 + A_v)} \text{ as before.}$$

8

The first thing to do in a question like this is work out the transfer function; this allows the pole and zero frequencies to be identified in terms of circuit components. Since the op-amp has infinite gain, the simple non-inverting gain expression can be used,

$$\frac{v_o}{v_i} = \frac{R_1 + \frac{R_2 \left( R_3 + \frac{1}{sC} \right)}{R_2 + R_3 + \frac{1}{sC}}}{R_1}$$

$$= \frac{R_1 R_2 + R_1 R_3 + \frac{R_1}{sC} + R_2 R_3 + \frac{R_2}{sC}}{R_1 R_2 + R_1 R_3 + \frac{R_1}{sC}}$$



$$\begin{aligned}
&= \frac{R_1 + R_2 + sC(R_1R_2 + R_1R_3 + R_2R_3)}{R_1(sC(R_2 + R_3) + 1)} = \frac{R_1 + R_2}{R_1} \frac{1 + sC \left( \frac{R_1R_2 + R_1R_3 + R_2R_3}{R_1 + R_2} \right)}{1 + sC(R_2 + R_3)} \\
&\equiv k_L \frac{1 + j \frac{\omega}{\omega_1}}{1 + j \frac{\omega}{\omega_0}} \text{ where } \omega_0 = \text{the pole frequency, } \omega_1 = \text{the zero frequency and } k \text{ is the}
\end{aligned}$$

low frequency gain. The high frequency gain,  $k_H$ , can be worked out directly from the circuit by letting  $C$  become a short circuit or it can be deduced from the transfer function by finding the limiting value of its modulus as frequency becomes very large. Three values are defined and this leads to three equations that must be solved simultaneously:-

$$\omega_0 = \text{pole frequency} = \frac{1}{C(R_2 + R_3)} = 2\pi 10 \quad (8.1)$$

$$\omega_1 = \text{zero frequency} = \frac{R_1 + R_2}{C(R_1R_2 + R_1R_3 + R_2R_3)} = 2\pi 500 \quad (8.2)$$

$$k_H = \text{high frequency gain} = \frac{R_1R_2 + R_1R_3 + R_2R_3}{R_1(R_2 + R_3)} = 10 \quad (8.3)$$

One of the many ways of solving these equations is as follows. Combining (8.2) and (8.3) to eliminate  $(R_1R_2 + R_1R_3 + R_2R_3)$  gives,  $\frac{R_1 + R_2}{10 C R_1 (R_2 + R_3)} = 2\pi 500$  and eliminating  $(R_2 + R_3)$  from this using (8.1) leaves  $\frac{(R_1 + R_2) 2\pi 10 C}{10 C R_1} = 2\pi 500$  or  $\frac{R_1 + R_2}{R_1} = 500$  so  $\frac{R_2}{R_1} = 499$ .  $R_1$  is given as  $10\text{k}\Omega$  so  $R_2 = 4.99\text{M}\Omega$ .

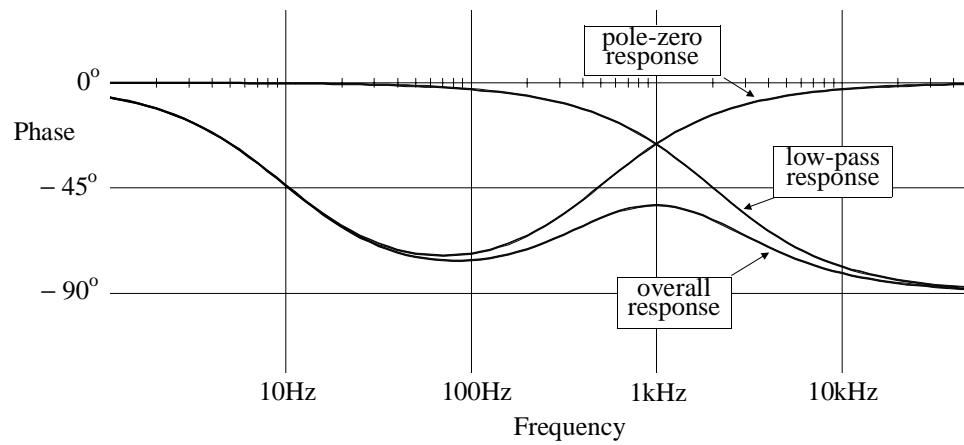
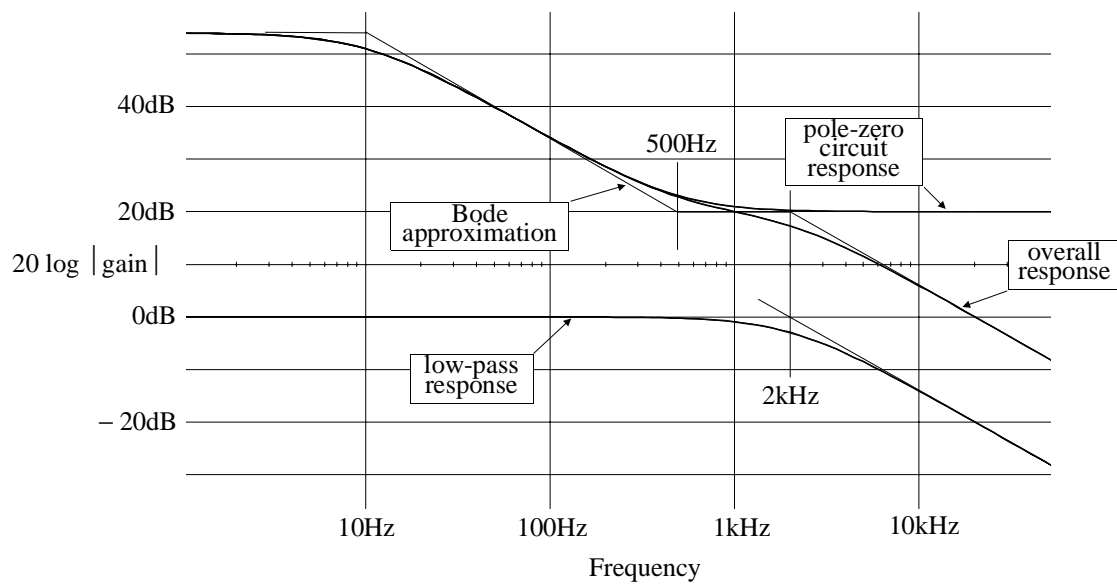
Two of the three resistor values are now known so (8.3) can be used to find  $R_3$  directly since it is the only unknown in that equation. Thus,

$$\frac{R_1R_2 + R_1R_3 + R_2R_3}{R_1(R_2 + R_3)} = 10 = \frac{10^4 \times 4.99 \times 10^6 + 10^4 R_3 + 4.99 \times 10^6 R_3}{10^4 (4.99 \times 10^6 + R_3)} \text{ or } R_3 = 91.6\text{k}\Omega$$

The value of  $C$  can be calculated using either (8.1) or (8.2); (8.1) is numerically simpler. By either route,  $C = 3.13\text{nF}$

The frequency response of the circuit can be drawn using the knowledge gained from problem sheet 1. Although adding a low pass circuit to the output makes the circuit second order, the additional low pass function is in series with the existing pole-zero function and thus on a log-log amplitude plot the amplitude and phase responses of the two circuits add. The overall response will be of the form:

$$\frac{v_o}{v_i} = k_L \frac{1 + j \frac{\omega}{\omega_1}}{\left(1 + j \frac{\omega}{\omega_0}\right) \left(1 + j \frac{\omega}{\omega_2}\right)} \text{ where } \omega_2 \text{ is the corner frequency of the extra low-pass circuit}$$



and  $k_L$ ,  $\omega_0$  and  $\omega_1$  are as before. The phase and amplitude response diagrams above show the pole-zero response, the extra low-pass response and the overall response. A Bode approximation has been included on the amplitude response.